

To our customers,

Old Company Name in Catalogs and Other Documents

On April 1st, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Phase-out/Discontinued

**SWITCHING
N-CHANNEL POWER MOS FET
INDUSTRIAL USE**

DESCRIPTION

This product is N-Channel MOS Field Effect Transistor designed for DC/DC converter and power management applications of note book computers.

FEATURES

- Low On-Resistance
 $R_{DS(on)1} = 27 \text{ m}\Omega \text{ Typ. (} V_{GS} = 10 \text{ V, } I_D = 3.5 \text{ A)}$
 $R_{DS(on)2} = 50 \text{ m}\Omega \text{ Typ. (} V_{GS} = 4 \text{ V, } I_D = 3.5 \text{ A)}$
- Low C_{iss} $C_{iss} = 850 \text{ pF Typ.}$
- Built-in G-S Protection Diode
- Small and Surface Mount Package (Power SOP8)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1700G	Power SOP8

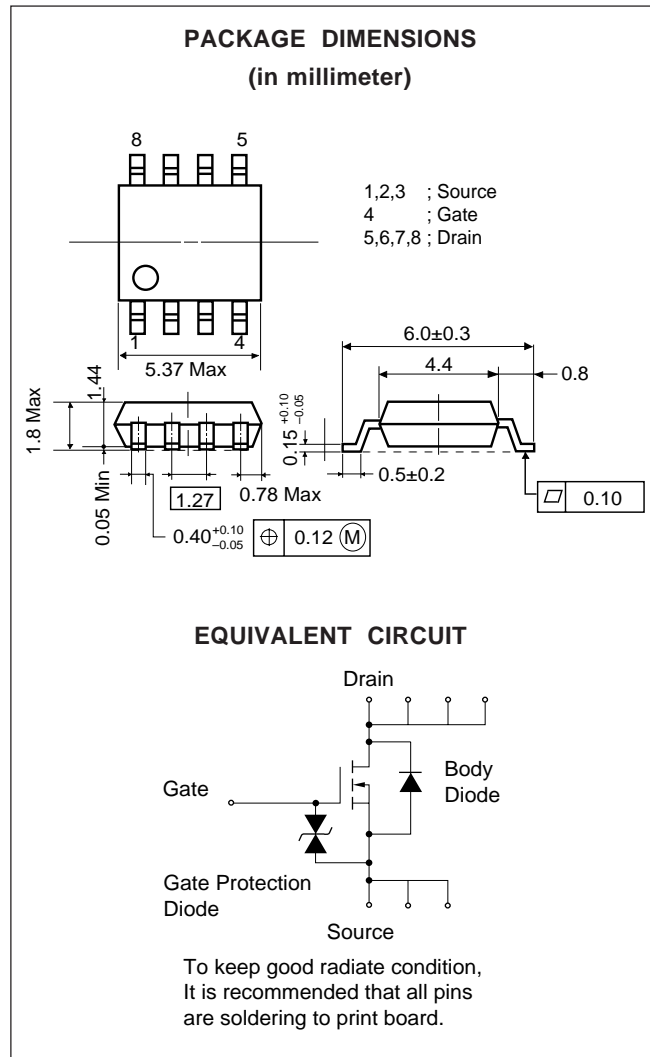
ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	V_{DSS}	30	V
Gate to Source Voltage	V_{GDS}	±20	V
Drain Current (DC)	$I_{D(DC)}$	±7.0	A
Drain Current (pulse)*	$I_{D(pulse)}$	±28	A
Total Power Dissipation	P_T	2.0	W
(TA = 25 °C)**			
Channel Temperature	T_{CH}	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

* $PW \leq 10 \mu s$, Duty Cycle $\leq 1 \%$

** Mounted on ceramic substate of $1200 \text{ mm}^2 \times 0.7 \text{ mm}$

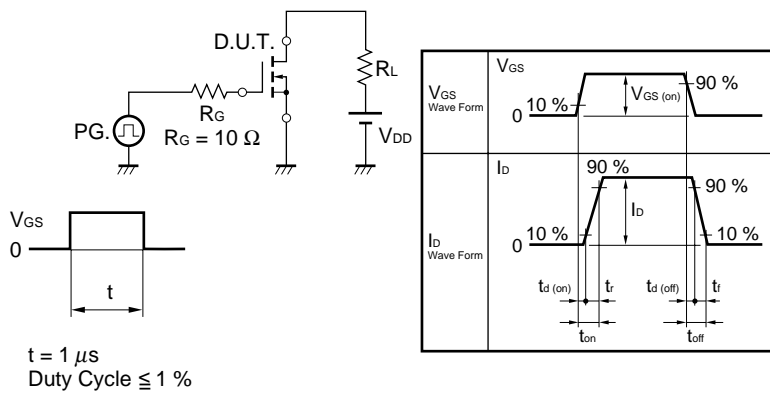
The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



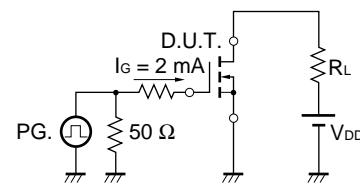
ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	R _{DS(on)1}	V _{GS} = 10 V, I _D = 3.5 A		20	27	mΩ
	R _{DS(on)2}	V _{GS} = 4 V, I _D = 3.5 A		33	50	mΩ
Gate to Source Cutoff Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.0	1.6	2.0	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 10 V, I _D = 3.5 A	5.0			S
Drain Leakage Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0			10	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0			±10	μA
Input Capacitance	C _{iss}	V _{DS} = 10 V		850		pF
Output Capacitance	C _{oss}	V _{GS} = 0		550		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		270		pF
Turn-On Delay Time	t _{d(on)}	I _D = 3.5 A		20		ns
Rise Time	t _r	V _{GS(on)} = 10 V		105		ns
Turn-Off Delay Time	t _{d(off)}	V _{DD} = 15 V		90		ns
Fall Time	t _f	R _G = 10 Ω		60		ns
Total Gate Charge	Q _G	I _D = 7.0 A		33		nC
Gate to Source Charge	Q _{GS}	V _{DD} = 24 V		2.4		nC
Gate to Drain Charge	Q _{GD}	V _{GS} = 10 V		13		nC
Body Diode Forward Voltage	V _{F(S-D)}	I _F = 7.0 A, V _{GS} = 0		0.84		V
Reverse Recovery Time	t _{rr}	I _F = 7.0 A, V _{GS} = 0		60		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		90		nC

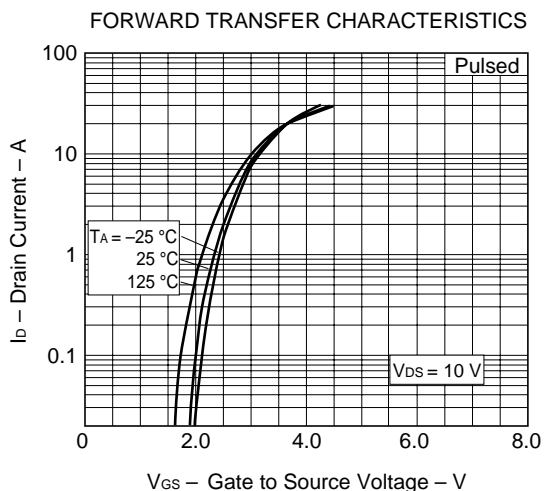
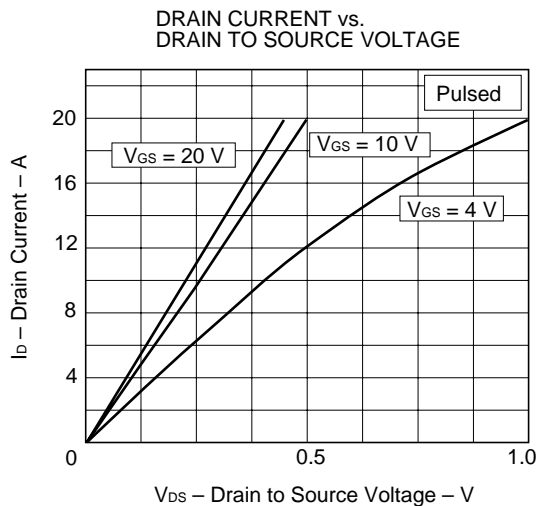
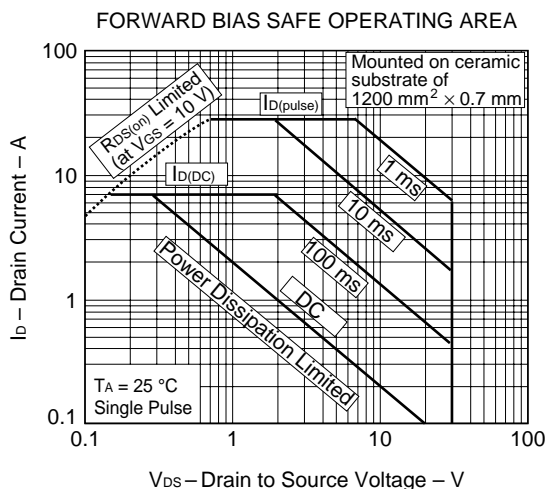
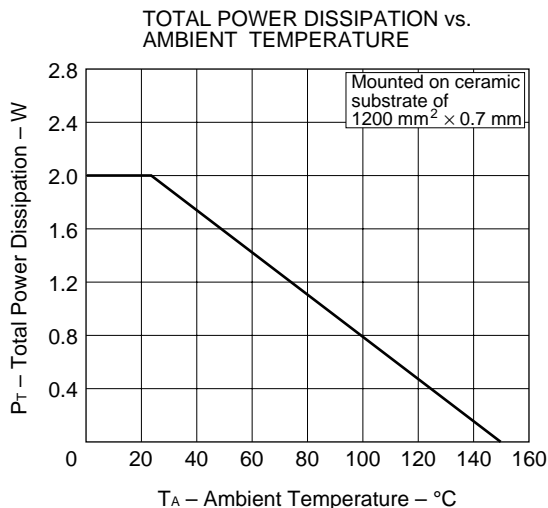
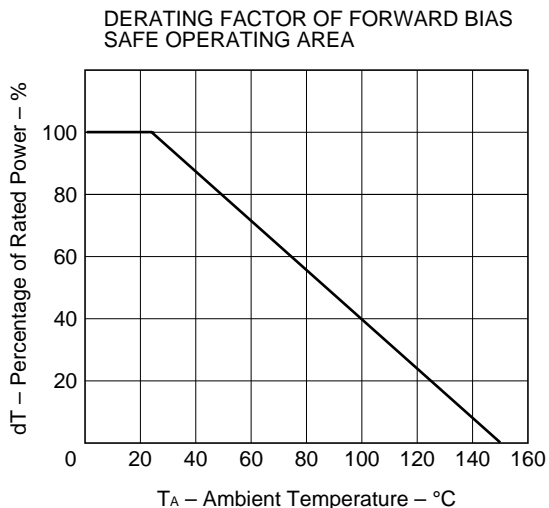
Test Circuit 1 Switching Time



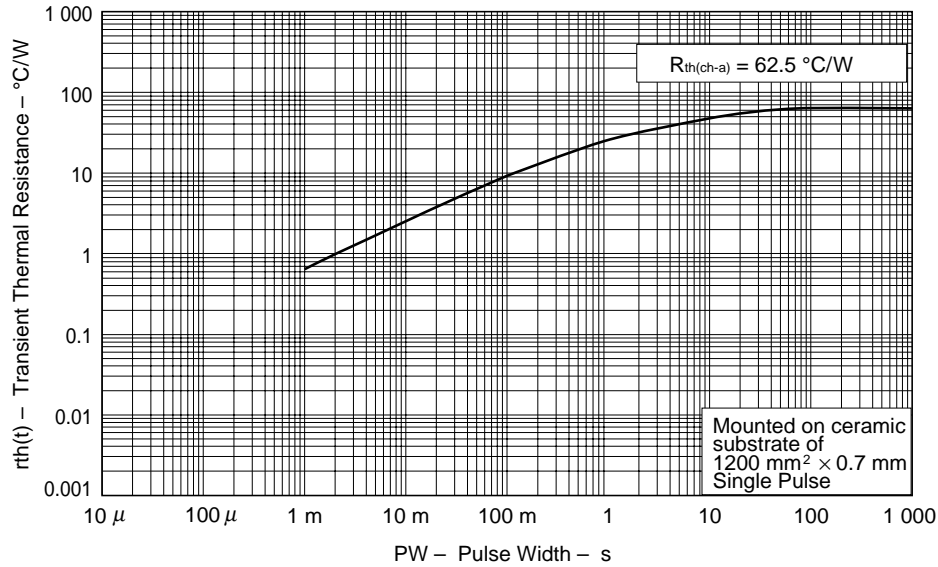
Test Circuit 2 Gate Charge



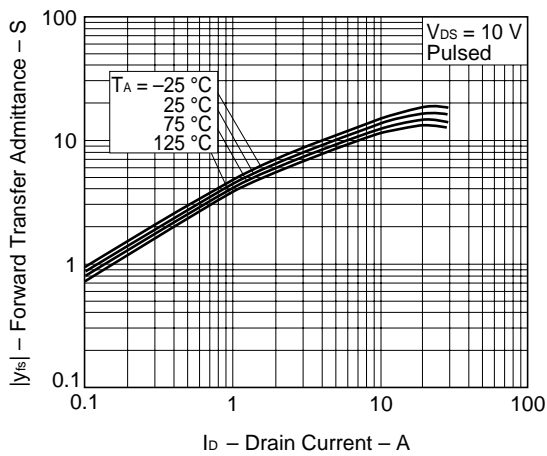
TYPICAL CHARACTERISTICS (T_A = 25 °C)



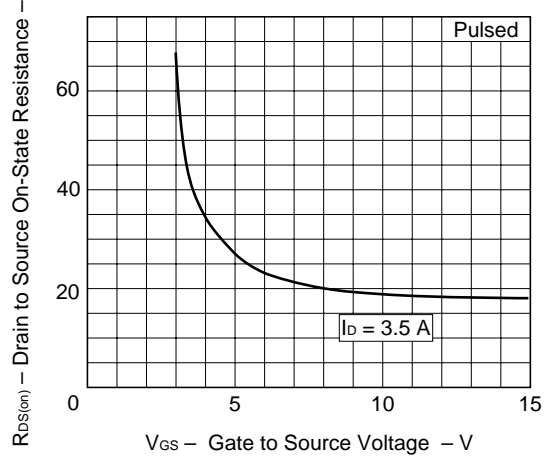
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



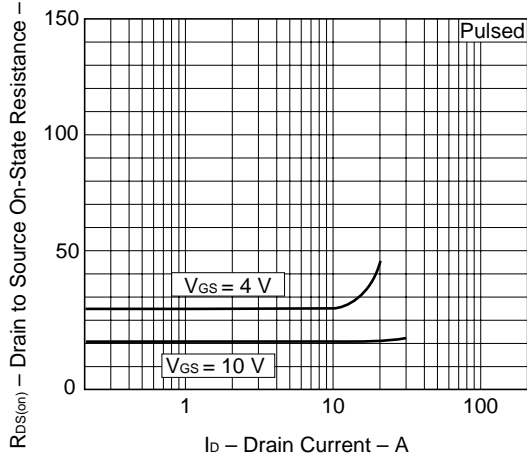
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



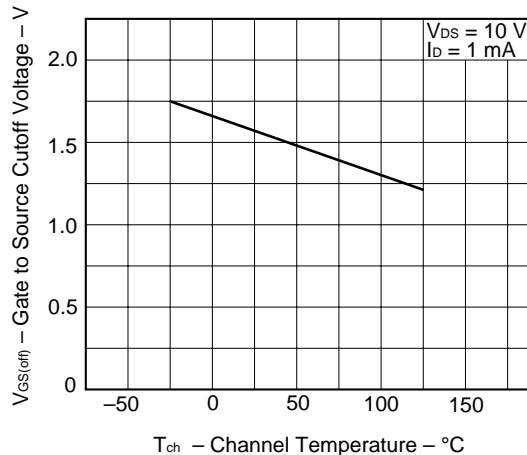
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

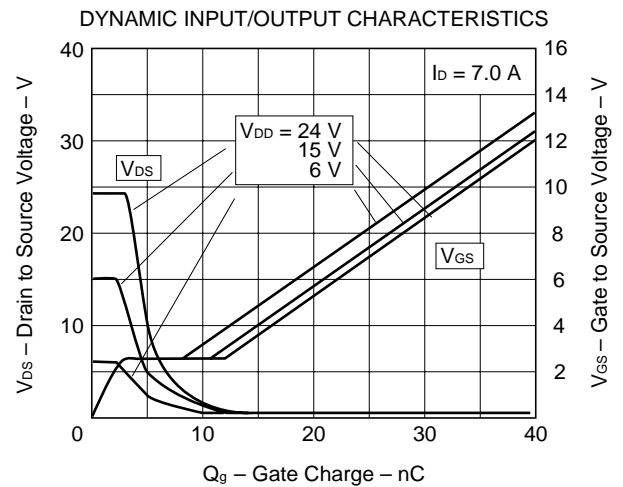
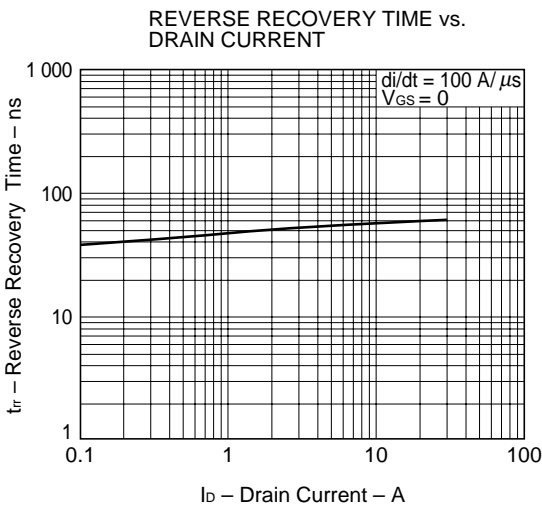
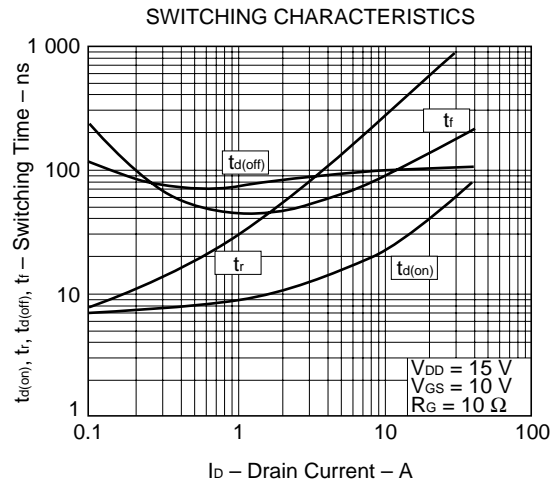
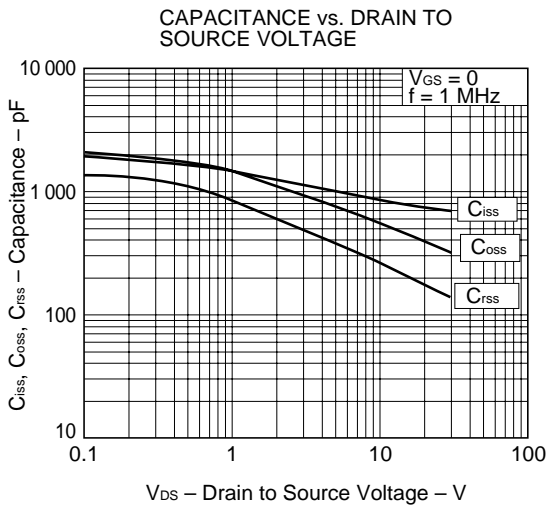
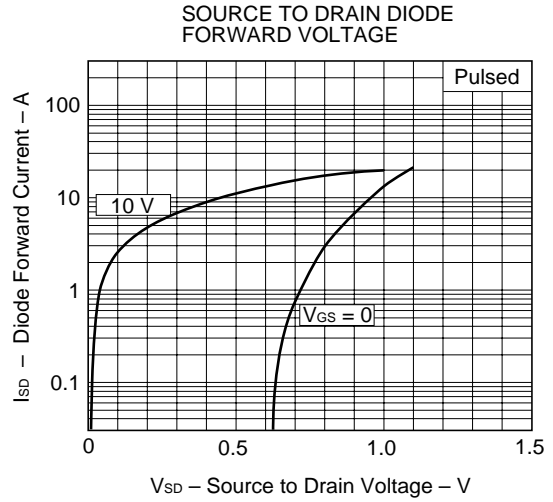
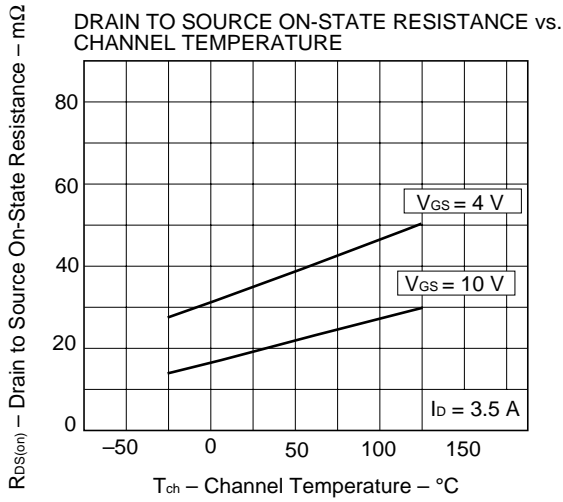


DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE





REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	IEI-1207
Semiconductor device package manual	IEI-1213
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	MF-1134
Power MOS FET features and application switching power supply	TEA-1034
Application circuits using Power MOS FET	TEA-1035
Safe operating area of Power MOS FET	TEA-1037

[MEMO]

[MEMO]

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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